

XIII School on Synchrotron Radiation: Fundamentals, Methods and Applications

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Photoemission Spectroscopy: Fundamental Aspects

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outline

1.Intruduction 2. Energy conservation, binding energy and photoelectron energy **3.Satellite structures and multiplet splitting 4.Chemical shift 5.Molecular photoelectron spectra 6.Photoelectron angular distributions** 7. Hole state relaxation 8. Resonant photoemission 9.Photoemission in solids **10.EDC and core ionization 11.Angular resolved PES**



He Iα=21.23eV He IIα=40.82eV Mg Kα1,2 = 1253,6 eV Al Kα1,2=1486,6eV Synchrotron Radiation

hv

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K.

 \mathbf{M}

E

Amp.

E_e

Counter

 $Je(hv, Ee, \theta, \phi, \sigma)$

н

Sample

ENERGY CONSERVATION, BINDING ENERGY AND PHOTOELECTRON ENERGY



X-section vs. Photoemission current

$$J_{e}(h\nu,\vartheta,\phi) = J_{h\nu}(\rho l) \int_{\Delta E \Delta \Omega} \frac{d\sigma}{d\Omega dE} F_{an}(E,\Omega) \eta_{det}(E) d\Omega dE$$

Photoemission peak lineshape

- 1. Photon monochromaticity
- 2. Electron analyzer resolution
- **3.** Final state lifetime (uncertainty principle)

Gaussian Gaussian Lorentian

Lineshape =Convolution (1,2,3)

The photoemission process



Interaction radiation matter

$$\frac{d\sigma}{dh\nu} = 4\pi^2 \alpha h \nu \sum_{B} \left| \hat{\varepsilon} \bullet \left\langle \Psi_{B} \right| \sum_{i} \vec{r}_{i} \left| \Psi_{A} \right\rangle \right|^{2} \delta(E_{B} - E_{A} - h\nu)$$

Bertoni's lecture this school

Initial state A = Neutral ground(excited) state Final state B = Residual ion + free electron(s)

Energy balance for 2e atom

$$E_B = E_A + hv$$

$$\Psi_A = \hat{A}\phi_1\phi_2 \qquad \Psi_B = \hat{A}\phi_1\varepsilon_2$$

$$E_{1s} + E_e = E_{1s} + E_{1s} + hv$$

$$E_e = hv - BE_{1s}(24.6eV)$$

One single photoemission peak is expected Energy and momentum are conserved

Complexity of the photoemission spectrum



The noble gas panorama



Primary photoionization process

PRIMARY PHOTOIONIZATION PROCESSES







 $M + h\nu \rightarrow M^+ + e^-$

 $M + h\nu \rightarrow M^{+*} + e^{-}$

Photon = single particle operator
 2 or more particles involved in final state = e-e correlation
 Relaxation & e-e correlation in photoemission = satellite



The He satellite structure



$$$$

sudden approximation

$$\left|\Psi_{B}^{(N)}\right\rangle = \hat{A}(\varepsilon_{l};\left|\Psi_{B}^{(N-1)}\right\rangle)$$

$$\frac{d\sigma}{d\Omega dE_e} \propto \frac{1}{h\nu} \sum_{A,B} \left| \hat{\varepsilon} \bullet \left\langle \varepsilon_l \right| \vec{r}_j \left| \phi_j(\vec{r}_j, \sigma_j) \right\rangle \left\langle \Psi_B^{(N-1)} \left| \Psi_R^{(N-1)} \right\rangle \right|^2 \delta(E_e + E_B^{(N-1)} - E_A - h\nu)$$

frozen core approvimation

$$H_0^{'} = H_0$$

$$\frac{d\sigma}{d\Omega dE_e} \propto \frac{1}{h\nu} \sum_{A,B} \left| \hat{\varepsilon} \bullet \left\langle \varepsilon_l \right| \vec{r}_j \left| \phi_j(\vec{r}_j, \sigma_j) \right\rangle \right|^2 \delta(E_e + \varepsilon_j - h\nu)$$

Total photoemission cross section



Photoelectron current vs. photoelectron energy





Spin orbit splitting







Chemical shift



Chemical shift vs.electronegativity





PES spectrum of N₂



Diatomic molecule e levels





Core PE vibrational spectrum







Rotational structure HF







Angular distributions




Fixed in space molecules CO C 1s



Application to surfaces



Core hole relaxation



Energy, angular momentum, Dipole selections at each step

Auger decay







Auger chemical shift



Autoionizing decay



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Ar Autoionization spectrum



46



Phys. Rev. A 63,032514



From central to periodic potential



Spectral Function in Interacting Solids

 $\Psi_{\rm Nf} = A \Psi^{\rm N-1}{}_{\rm f} \Phi_{\rm kf}$

 $Je \propto \Sigma_{if} |\mathbf{M}_{if}^{2}| \Sigma_{m} |\mathbf{m}_{im}|^{2} \times \delta(\mathbf{E}_{i}^{N} + \mathbf{hv} - \mathbf{E}_{m}^{N-1} - \mathbf{E}_{kin})$ $A(k, \varepsilon) = \Sigma_{m} (|\langle \Psi^{N-1}_{m} |\mathbf{c}_{k} | \Psi^{N}_{i} \rangle)|^{2} \times \delta(\varepsilon + \mathbf{E}_{m}^{N-1} - \mathbf{E}_{i}^{N})$ $Je(k, \omega) \propto \Sigma_{if} |\mathbf{M}_{if}|^{2} A(k, \mathbf{E}_{kin} - \mathbf{hv}) f(\mathbf{E}_{kin} - \mathbf{hv})$

For non interacting particles $A(\varepsilon, k) = \delta(\varepsilon - E_k)$ where $E_k = E_i^{N-1} - E_i^N$

 $A(\varepsilon, k) = 1/\pi \left| \Sigma''(k, \varepsilon) \right| / \left[\left| \varepsilon - \mathbf{E}_{k} - \Sigma'(k, \varepsilon) \right|^{2} + \left| \Sigma''(k, \varepsilon) \right|^{2} \right]$



The Three-Step model 1



The three-step model 2

1. Dipole transition

 $Je = \sum_{if} f(E_i) \left[1 - f(E_f)\right] M^2_{if} \times \delta[E_{kin} - (E_f - \Phi)] \delta(E_f - E_i - h\nu) \delta(k_i + G - k_f)$

2. Elastic transport

 $d(E_f, k) = \alpha \lambda / (1 + \alpha \lambda)$

3. Exit to vacuum

$$\Gamma(E_{f}, k_{ext}) = \begin{cases} 0 \text{ if } E_{f} < E_{F} + \Phi \\ 1/2 \sqrt{[1-(E_{F} + \Phi)/Ef]} \text{ if } E_{f} > E_{F} + \Phi \end{cases}$$

Total current

$$\begin{split} Je &\propto \Sigma_{if} \ f(E_i) \ [1\text{-}f(E_f)] \ M^2_{if} \times T(E_f, \, k_{ext}) \times d(E_f, \, k) \times \delta[E_{kin}\text{-}(E_f\text{-}\Phi)] \ \delta(E_f\text{-}E_i\text{-}h\nu) \times \delta \ (k_i\text{+}G\text{-}k_f) \times \delta \ (k_i^{\prime\prime}\text{+}G^{\prime\prime}\text{-}k_{ext}^{\prime\prime}) \end{split}$$



How to reconstruct the initial state



Valence band EDC and Cooper minimum



Valence Band EDCs of the clean Pt(997) surface (thin lines) and of Co-nanowires grown on Pt(997) (dots and thick lines), taken at different photon energies

Resonant photoemission





Valence Band EDCs of a CuPc thin-film taken at different photon energies (left panel) and X-ray Absorption Spectroscopy (XAS) from the same CuPc across the N Kedge (right panel).

2D electron gas spatially confined Cs/InAs(110)



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Photoemission Spectroscopy

Core level XPS spectrum of graphite (C)



The singlet C 1s line is characterized by:

1) A specific binding energy which reflects the specific atomic species (C) in a specific chemical environment

2) A finite width reflecting the instrumental resolution, lifetime broadening and other many-body effects

Photoemission Spectroscopy: Chemical Shift (ΔE_b)



How the C 1s binding energy reflects differing chemical environme nt local to the excited C sites



FIG. 1. Intermediate-oxidation states at the SiO₂/Si(100) interface, identified by their Si 2p core-level shifts. The top curve represents the raw photoemission data for the Si $2p_{1/2,3/2}$ core levels. The bottom curve has the Si $2p_{1/2}$ line and the secondary electron background subtracted. All three intermediateoxidation states are seen. For a truncated bulk structure only Si²⁺ would be present since the Si(100) surface has two broken bonds per atom. Core Levels, chemical shift

The Si 2p line is characterized by the occurrence of 5 chemically distinct components which reflect different chemical states of the Si atoms at the interface

Surface core level shift vs. mean free path In 4d



Highresolution In-4d core-levels at freshly cleaved InAs(110), taken with He_{IIa} and He_{IIb} radiation; Voigt-profiled fit with surface (S, blu lines) and bulk (B, red lines) doublet components (left panel)



valence PE vibrational spectrum



pentacene: C22H14

benzene-thiol: C₆H₅-SH







Betti, Kanjilal and Mariani, J. Phys. Chem. A **111**, 12454 (2007)

Cooper Minimum Photoemission It is possible when one of the valence band orbital shows a Cooper minimum in the photoionization cross section



Cooper Minimum Photoemission A joint analysis of VB photoemission spectra taken at and off the Cooper minimum enables one to disentangle the differing site- and orbital-specific contributions



Analysis of the Si sp partial DOS at the Pt-Si(111) reacted interface (40 Å Pt-Si(111) at room temperature). The top panel displays the CM and the $h\nu = 80$ eV photoemission data, and a three-peak partial DOS that accounts for the Si hybridized 3sp charge at the interface; a gap is present in correspondence to the localized Pt5d states. The same three-peak partial DOS is then self-convoluted and compared to the integrated SiL_{2,3}VV lineshape. The correspondence of all peaks and relative intensities (a part of the known reduction of the Si 3s contribution) confirms the CM derivation of the Si sp partial DOS [159].

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Angular resolved photoemission







Dangling bonds Si(111)-(2x1)



Dangling-bond surface state dispersion at the Si(111)-(2x1) reconstructed surface along the ΓJ direction of the Surface Brillouin Zone (SBZ). One of the first experimental ARPES dangling-bond dispersion (left panel); recent high-resolution ARPES dangling-bond dispersion.

Physisorbed Xe c(2x2)/Cu(110)



Experimental band structure of the 5p levels of Xe physisorbed in an ordered $c(2\times 2)$ structure onto the Cu(110) surface. ARPES bands



2-nm thick pentacene film grown on Cu(119). ARPES selection of spectra taken at normal emission and varying the photon energy (left); highest-occupied molecular-orbital (HOMO) band dispersion along k_{\perp} (right).
ARPES graphite (HOPG)





Valence band of graphite (HOPG), stacking of the ARPES spectra as a function of polar angle (left) and experimental band structure (right).

Graphene band structure



Graphene band structure along GKM and zoom of the Dirac cone around the K point of the SBZ. ARPES data taken with high-resolution ARPES and a He discharge source

Band formation in graphene multilayers



• Formation of an electronic band, stepwise: from 1-layer (extreme left) to 4-layer (extreme right) graphene band structure along across the Dirac point.

K shell dispersion in graphene



Photoelectron Spectroscopy XIII SILS School G. Stefani Spectral function of the C 1s core-level in graphene as a function of the emission polar angle

Silvano Lizzit, et al.: Nature Physics 6, 345-349 (2010)

The End

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